Coexistence of superconductivity and ferromagnetism in a dilute cobalt-doped La$_{1.89}$Ce$_{0.11}$CuO$_{4+\delta}$ system

National Laboratory for Superconductivity, Institute of Physics and Beijing National Laboratory for Condensed Matter Physics, Chinese Academy of Sciences, P. O. Box 603, Beijing 100080, China 
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Thin films of the optimally electron-doped $T^*$-phase superconductor La$_{1.89}$Ce$_{0.11}$CuO$_{4+\delta}$ are investigated by dilute Co doping, forming La$_{1.89}$Ce$_{0.11}$(Cu$_{1-x}$Co$_x$)$_{0.8}$O$_{4+\delta}$ (LCCCO) with $x=0.01-0.05$. The following results are obtained: for the whole dilute Co doping range, LCCCO thin films show long-range ferromagnetic ordering in the temperature range from 5 to 300 K, which is likely due to the Ruderman-Kittel-Kasuya-Yosida interaction; for very dilute Co doping, $x=0.01$ and 0.02, the superconductivity is maintained, and the system shows the coexistence of superconductivity and ferromagnetism in the CuO$_2$ plane. This may be based on the nature of the charge carriers in electron-doped high-$T_c$ cuprate superconductors.

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An important step forward in superconductor physics is the observation of the coexistence of superconductivity (SC) and ferromagnetism (FM) in the spin-triplet pairing superconductors, such as UGe$_2$, ZrZn$_2$, and URhGe. For high-$T_c$ cuprate superconductors (HTSCs), it is commonly believed that the CuO$_2$ plane plays an important role in the SC. Therefore, seeking for the possibility of coexistence of SC and FM in the CuO$_2$ plane is very helpful for us to understand the interaction between SC and magnetism, and the mechanism of SC. Ru$_2$Sr$_2$GdCu$_2$O$_8$ (Ru-1212) is well known for the feature of coexistence of SC and FM, but a study of the coexistence of SC and FM at temperatures below $T_c$ in the RuO$_2$ plane has been an important issue for HTSCs. Much work has been done on the substitution of a magnetic Ni ion (Fe, Co, etc., are also included in some work) for a Cu ion in (La,Sr)$_2$CuO$_4$, YBa$_2$Cu$_3$O$_y$, Bi$_2$Sr$_2$CaCu$_2$O$_8$, and their related compounds. For comparison, the same work has been done on the nonmagnetic Zn ion substitution. The study of the impurity doping effect has provided a great deal of information about the nature of the cuprates. However, there have been no reports on the possible coexistence of SC and FM in the CuO$_2$ plane.

It should be particularly pointed out that most of the previous experiments on the magnetic impurity doping effect are focused on hole-doped HTSCs, and only a few works have been addressed to the electron-doped ones. This is mainly attributable to the relatively lower $T_c$ ($\leq 30$ K) and more complicated preparation process of the electron-doped HTSCs. However, the electron-doped HTSCs have their own intriguing properties, especially since the two-band model and two types of charge carriers (electrons and holes) are confirmed experimentally and theoretically. It will be interesting and challenging for us to deeply explore the interaction of SC and FM related to the CuO$_2$ plane by magnetic impurity doping in the electron-doped HTSCs, since even for the case of Ru-1212, the two-band model and two kinds of charge carriers are considered to be the origin of the coexistence of SC and FM.

In the present work, thin films of the optimally electron-doped $T^*$-phase superconductor La$_{1.89}$Ce$_{0.11}$CuO$_{4+\delta}$ (LCCO) are investigated by dilute Co doping at the Cu site. Through systematic transport and magnetization measurements of La$_{1.89}$Ce$_{0.11}$(Cu$_{1-x}$Co$_x$)$_{0.8}$O$_{4+\delta}$ (LCCCO) thin films with $x=0.01-0.05$, together with reduction treatment and valence examinations, some interesting effects are found, contrasting with previous work: long-range FM ordering is observed in the temperature range of 5–300 K for all the Co doping concentrations $x=0.01-0.05$, and is suggested to be formed by the Ruderman-Kittel-Kasuya-Yosida (RKKY) interaction; For cases of very dilute Co concentrations $x=0.01$ and 0.02, the coexistence of SC and FM at temperatures below $T_c$ in the CuO$_2$ plane is obviously detected; the electrons play an important role for SC in the LCCO system.

The optimally doped LCCO is used as the benchmark material for the present Co doping study; since its normal state is in a completely metallic phase and it has the highest $T_c$ ($\sim 30$ K) in the electron-doped HTSC family, we can easily test the influence of Co substitution for Cu on SC at relatively high temperatures. The condition of preparation of LCCCO thin films is similar to the case of LCCO as described in detail elsewhere. Stoichiometric targets with the atomic ratio of La:Ce:Cu:Co=1.89:0.11:(1–x):x were fabricated by a solid state reaction process. Then LCCCO thin films with $x=0.01$, 0.02, 0.04, and 0.05 were deposited on (001)-oriented SrTiO$_3$ (STO) substrates by dc magnetron sputtering to thickness of $\sim 250$ nm. X-ray diffraction (XRD) data show that all the thin films are in a single $T^*$ phase and (001) oriented. Figure 1 shows the [010] zone axis high-resolution electron microscopy (HREM) image and the corresponding electron diffraction pattern of the film with $x=0.05$, which indicates a perfect structure. In order to examine the electric and magnetic properties, the in-plane resistivity and magnetization were measured. All measurements were carried out using Quantum Design MPMS-5 equipment. In order to measure the resistivity, the samples were patterned into bridges with width of 50 $\mu$m. Then Ag electrodes were deposited on the surfaces of the films through a metal mask. The in-plane resistivity $\rho_{ab}(T)$ data as shown in Fig. 2(a) indicate that the samples with $x=0.01$ and 0.02 are superconducting, with zero-resistance temperature $T_{c0}\sim 13$
and $<5$ K, respectively. $T_{c,0}$ is $\sim 27$ K for a pure LCCO thin film (with $x=0$). The samples with $x=0.04$ and 0.05 tend to be insulatorlike with decreasing $T$ down to 5 K. The magnetization versus temperature $M(T)$ curves, with magnetic field $H=1000$ Oe (parallel to the CuO$_2$ plane), show the evolution from superconductor to ferromagnet with increasing Co concentration. Magnetization $M(H)$ measurements are also done for all the designed Co-doped thin films, and the clear hysteresis loops indicate that a real FM long-range ordering rather than some other magnetic phase$^{16}$ forms even for the very dilute Co concentration $x=0.01$. With increasing Co concentration, the FM ordering is enhanced. It can be clearly observed in Fig. 2(b) that the saturation magnetization $M_s$ for the film with $x=0.05$ is more than ten times larger than that of the film with $x=0.01$.

Surprisingly, $M(H)$ data for the samples with $x=0.01$ and 0.02 definitely show the coexistence of SC and FM in the superconducting transition region. In Fig. 3, four typical $M(H)$ curves are presented. Figure 3(a) shows a superconducting $M(H)$ curve for the sample with $x=0.01$ observed at a temperature ($T=5$ K) lower than $T_{c,0}$. In Fig. 3(b) the full ferromagnetic hysteresis loop for the same sample at 30 K (higher than $T_c$) is given. In Fig. 3(c) the $M(H)$ data of the sample with $x=0.02$ give clear evidence for the shielding effect in the low-field region (indicated by OM, with $H_{c1}$ of $\sim 50$ Oe at 5 K). However, with increasing $H$, SC is suppressed and FM becomes dominant in the sample. In Fig. 3(d), with increasing temperature up to 25 K (higher than $T_{c,0}$), the curve for the same sample with $x=0.02$ is transformed into a full FM hysteresis loop. These four loops obviously reveal the coexistence and competition of SC and FM at very dilute Co concentrations.

For the origin of FM ordering in LCCCO, several possibilities should be considered.$^{17}$ One is the segregated Co clusters that can be formed if the Co atoms cannot dissolve into the lattice of the LCCO. If such dilute Co atoms gather to form a FM, a large area of the film must be Co-ion-free, which results in separation of the SC base with a few FM clusters, and then no influence of Co doping on SC can be observed. Furthermore, we grew (103)-oriented LCCCO thin films on miscut (110)-oriented STO substrates in the same batch with the (001)-oriented sample. The process is similar to the growth of (103)-oriented LCCCO thin films.$^{14}$ The magnetization data show that the $M_s$ in the (103) plane is $\sim 1.4 \times 10^{-5}$ emu, obviously smaller than the $M_s \sim 1.8 \times 10^{-5}$ emu in the (001) plane. Such anisotropy of $M_s$ strongly suggests that the FM ordering does not originate from the segregated Co clusters. Actually, no Co cluster is observed in other Co-doped systems, such as Co-doped SnO$_2$ (Ref. 18) and ZnO,$^{17}$ in which long-range FM ordering with Curie temperature higher than room temperature is formed, while no Co cluster is observed. Another possible origin of the FM ordering, i.e., the Co oxides, can also be excluded, because almost all of the Co oxides are antiferromagnetic or ferrimagnetic.

![FIG. 1. The [010] zone axis HREM image (a) and its corresponding electron diffraction pattern (b) of LCCCO sample with Co concentration $x=0.05$.](image1)

![FIG. 2. (Color online) (a) In-plane resistivity $\rho_{ab}$ versus temperature for the films with Co concentration $x=0.01, 0.02, 0.04, 0.05$. Inset: $\rho_{ab}(T)$ of the reduction-treated film (after three times annealing) with $x=0.01$. (b) $M_s(x)$ obtained by from the two-dimensional (2D) damped RKKY model characterization, normalized by $M_s(x=0.01)$ with $f=50$ Å, $k_F=0.8$ Å$^{-1}$. Triangles and diamonds represent experimental data and calculated value, respectively. Solid line is the fit for the data. The error bars are from the statistical errors for 100 calculations. Inset: typical oscillating behavior of $G(R)F(k R)$ versus $k R$ for the thin film with $x=0.02$.](image2)
and $S$ (spin), the Co-ion distribution function $G(R)$, and the oscillating function $F(k_F R)$. If the sum of Eq. (1) is negative, FM can be achieved favorably. For each Co doping case, we make calculations in a 2D $2500 \times 2500$ lattice and average over 100 times. Since this sum is not sensitive to $k_F$ so long as we make sure it is negative (FM forms), it is reasonable to choose $k_F=0.8$ Å$^{-1}$. We set $l=50$ Å in order to keep the carriers moving well. Then the reduced $M_S$ for each Co concentration is obtained from the sum of $\exp(-R/l)G(R)F(k_F R)$, which is reduced by $M_S(x=0.01)$ as shown in Fig. 2(b). The calculations of $M_S$ are in agreement with the experimental data except for the sample with $x=0.05$, where a large bias between the theoretical calculation and the experimental data may be caused by the crossover of FM ordering from 2D to 3D. The inset of Fig. 2(b) shows the oscillating behavior of the RKKY interaction for $x=0.02$. This calculation clearly indicates that with increasing Co concentration, the RKKY interaction is the enhanced due to the decrease of distances between Co ion moments. It also indicates that the RKKY interaction is the dominant mechanism for the long-range FM ordering. Compared with other magnetic impurity doping, such a strong RKKY interaction may originate from the features of Co, e.g., strong $s$-$d$ electrons exchange interaction and high Curie temperature. Such strong RKKY interaction has also been observed in other Co-doped compounds. The RKKY interaction needs the charge carriers in the CuO$_2$ plane, and the charge carriers must also be responsible for the SC in the superconducting state. How can we resolve these two roles of charge carriers in the CuO$_2$ plane? We consider that the existence of two types of charge carriers in electron-doped HTSCs may be important. Previous work has suggested that the two-band model and two kinds of charge carriers in Ru-1212 take responsibility for the existence of SC and FM. Of course, understanding the origin of such coexistence of SC and FM in LCCCO should be probed further.

In order to understand the possible role of charge carriers in SC and FM ordering further, a reduction treatment is carried out for the sample with $x=0.01$, through which the relative strengths of SC and FM is changed by adjusting the concentrations of charge carriers. The samples with $x=0.01$ were annealed at $\sim 600$ K in $\sim 10^{-5}$ Pa vacuum for several minutes. The key in this process is to partially remove the oxygen from the films, but maintain the single $T'$ phase. After the treatment, XRD data show that the films are still single $T'$ phase. Figure 4(a) shows the evolution of $M_S$ with the annealing times. It shows that at 15 K $M_S$ is about 2.8 times larger after the first annealing in vacuum, and then stays almost constant for the further annealing steps, whereas $T_{c0}$ decreases from 13 K before the reduction treatment (the case of as-apical-oxygen removal, i.e., the highest $T_c$) to $<5$ K after the third annealing.

In order to reveal the origin of the changes of SC and FM with reduction treatment, x-ray photoelectron spectroscopy (XPS) measurements were performed with an AXIS-Ultra instrument from Kratos. The valences of La, Ce, Co, and Cu were tested before and after the reduction treatment. The results clearly show that after reduction treatment, the main peak of the Cu $2p_{3/2}$ state changes from 934.3 to 932.5 eV, and the ratio of the peak $2p_{3/2}$ satellite peak to the Cu $2p_{3/2}$
The oxygen was removed first from the CuO$_2$ plane with the RKKY interaction enhanced ($M_s$) increases after reduction treatment, so the concentration of holes possibly increases (the RKKY interaction needs the charge carriers). From the Hall measurements as shown in Fig. 4(c), we find that the Hall coefficient is indeed shifted toward the positive direction after reduction treatment. Therefore, the decrease of $T_c$ should be attributed to the reduction of the concentration of electrons. This means that the electrons may play an important role for SC in the LCCO, which seems to be different from the point of view that the holes are more important to SC in the NCCO.

In conclusion, optimally doped LCCO thin films are investigated by dilute magnetic impurity Co doping at the Cu site. It is observed that long-range FM ordering appears in the temperature range from 5 to 300 K for all the LCCCO thin films, $x=0.01$–0.05, and is suggested to be formed by the RKKY interaction; the coexistence of SC and FM is observed at very dilute Co concentrations $x=0.01$ and 0.02, below $T_c$. The existence of two kinds of charge carriers in the electron-doped HTSCs is suggested to be an important reason to such coexistence. However, other reasons, such as that the Co ion may have some special feature when it is doped in an electron-doped HTSC, should also be considered. Based on the reduction experiment, we argue that the electrons play an important role for SC in LCCO system. We believe that the present work provides additional information for understanding the intrinsic features of the electron-doped HTSCs.

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FIG. 4. (Color online) (a) $M_s$ (squares) and $T_c$ (circles) versus annealing time. The reduction treatment enhances FM to high level, whereas $T_c$ is decreased remarkably, caused by the reduction of the valence of Cu. (b), (c) Cu 2$p_{3/2}$ core-level XPS spectra and Hall coefficient of the cases of as-apical-oxygen removal and reduction-treated LCCCO with $x=0.01$, respectively.

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*Electronic address: brzhao@aphy.iphy.ac.cn*


